

**AMENDMENTS:**

**AMENDMENTS TO THE CLAIMS:**

This listing of claims will replace all prior versions, and listings, of  
5 claims in the application.

Please amend claims 1, 9, 15, 16 and 30, as follows:

1 (Currently Amended). An apparatus for frequency control, ~~eontrol of a resonator, the resonator adapted to provide a first signal having a resonant frequency,~~ the apparatus comprising:  
10 a reference resonator, the reference resonator adapted to provide a first signal having a resonant frequency;  
an amplifier coupled coupleable to the reference resonator; and  
15 a frequency controller coupled to the amplifier and coupled to the reference coupleable to the resonator, the frequency controller adapted to modify the resonant frequency of the reference resonator in response to at least one variable of a plurality of variables.

20 2 (Original). The apparatus of claim 1, wherein the plurality of variables comprise temperature, fabrication process, voltage, and frequency.

3 (Original). The apparatus of claim 1, wherein the amplifier further comprises a negative transconductance amplifier.  
25 4 (Original). The apparatus of claim 3, wherein the frequency controller is further adapted to modify a current through the negative transconductance amplifier in response to temperature.

30 5 (Original). The apparatus of claim 4, wherein the frequency controller further comprises a current source responsive to temperature.

6 (Original). The apparatus of claim 5, wherein the current source has one or more configurations selected from a plurality of configurations, the plurality of configurations comprising CTAT, PTAT, and PTAT<sup>2</sup> configurations.

5 7 (Original). The apparatus of claim 3, wherein the frequency controller is further adapted to modify a current through the negative transconductance amplifier to select the resonant frequency.

8 (Original). The apparatus of claim 3, wherein the frequency controller is further  
10 adapted to modify a transconductance of the negative transconductance amplifier to select the resonant frequency.

9 (Currently Amended). The apparatus of claim 3, claim 14, wherein the frequency controller is further adapted to modify a current through the negative  
15 transconductance amplifier in response to a voltage.

10 (Original). The apparatus of claim 3, wherein the frequency controller is further adapted to modify a transconductance of the negative transconductance amplifier in response to fabrication process variation.

20 11 (Original). The apparatus of claim 3, wherein the frequency controller is further adapted to modify a current through the negative transconductance amplifier in response to fabrication process variation.

25 12 (Original). The apparatus of claim 1, wherein the frequency controller further comprises a voltage isolator coupled to the resonator and adapted to substantially isolate the resonator from a voltage variation.

30 13(Original). The apparatus of claim 12, wherein the voltage isolator comprises a current mirror.

14 (Original). The apparatus of claim 13, wherein the current mirror has a cascode configuration.

15 (Currently Amended). The apparatus of claim 1, wherein the reference resonator is one or more of the following resonators: selected from a group comprising: an inductor (L) and a capacitor (C) configured to form an LC-tank resonator; a ceramic resonator, a mechanical resonator, a microelectromechanical resonator, and a film bulk acoustic resonator.

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16 (Currently Amended). An apparatus, comprising:

a reference resonator, the reference resonator adapted to provide a first signal having a resonant frequency;

10 a negative transconductance amplifier coupled to the reference resonator; and

a temperature compensator coupled to the negative transconductance amplifier and to the reference resonator, the temperature compensator adapted to modify the resonant frequency in response to temperature.

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17 (Original). The apparatus of claim 16, wherein the temperature compensator is further adapted to modify a current through the negative transconductance amplifier in response to temperature.

20 18 (Original). The apparatus of claim 17, wherein the temperature compensator further comprises a current source responsive to temperature.

19 (Original). The apparatus of claim 18, wherein the current source further comprises:

25 a first transistor;  
a second transistor coupled to the first transistor;  
a diode coupled to the first transistor; and  
a resistor coupled to the second transistor.

30 20 (Original). The apparatus of claim 19, wherein the current provided by the current source is a function of a voltage across the diode and a resistance of the resistor, wherein the voltage and the resistance are temperature-dependent.

21 (Original). The apparatus of claim 19, wherein the first and second transistors are operable in strong inversion.

22 (Original). The apparatus of claim 18, wherein the current source further

5 comprises:

- a first transistor;
- a second transistor coupled to the first transistor; and
- a resistor coupled to the second transistor.

10 23 (Original). The apparatus of claim 22, wherein the current provided by the current source is a function of a voltage across the resistor, a resistance of the resistor, and respective sizes of the first and second transistor, wherein the voltage and the resistance are temperature-dependent.

15 24 (Original). The apparatus of claim 22, wherein the first and second transistors are operable at a subthreshold voltage.

25 (Original). The apparatus of claim 18, wherein the current source further comprises:

20 a plurality of transistors; and  
a resistor coupled to a transistor of the plurality of transistors.

26 (Original). The apparatus of claim 25, wherein the current provided by the current source is a function of a square of a voltage across the resistor, wherein the voltage is 25 temperature-dependent.

27 (Original). The apparatus of claim 25, wherein a first set of transistors of the plurality of transistors are operable in strong inversion and a second set of transistors of the plurality of transistors are operable at a subthreshold voltage.

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28 (Original). The apparatus of claim 18, wherein the current source has one or more configurations selected from a plurality of configurations, the plurality of configurations comprising CTAT, PTAT, and PTAT<sup>2</sup> configurations.

29 (Original). The apparatus of claim 18, wherein the current source is coupled through one or more current mirrors to the negative transconductance amplifier.

5 30 (Currently Amended). An apparatus, comprising:

a reference resonator, the reference resonator adapted to provide a first signal having a resonant frequency;

a negative transconductance amplifier coupled to the reference resonator;

10 a current mirror coupled to the negative transconductance amplifier; and a current source coupled to the current mirror, the current source adapted to modify the resonant frequency of the reference resonator by varying a current through the current mirror and the negative transconductance amplifier in response to temperature.

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31 (Original). The apparatus of claim 30, wherein the current source has one or more configurations selected from a plurality of configurations, the plurality of configurations comprising CTAT, PTAT, and PTAT<sup>2</sup> configurations.

20 32 (Original). The apparatus of claim 31, further comprising a plurality of current sources coupled to the current mirror, the a plurality of current sources having at least two configurations selected from a plurality of configurations, the plurality of configurations comprising CTAT, PTAT, and PTAT<sup>2</sup> configurations.

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